Clock OSC SG5032CCN

SEIKO EPSON CORPORATION

Product name SG5032CCN 5.550000 MHz HJGA

Product Number / Ordering code X1G0044710039xx

Please refer to the 8.Packing information about xx (last 2 digits)

Output waveform CMOS

Pb free / Complies with EU RoHS directive

Reference weight Typ. 52 mg

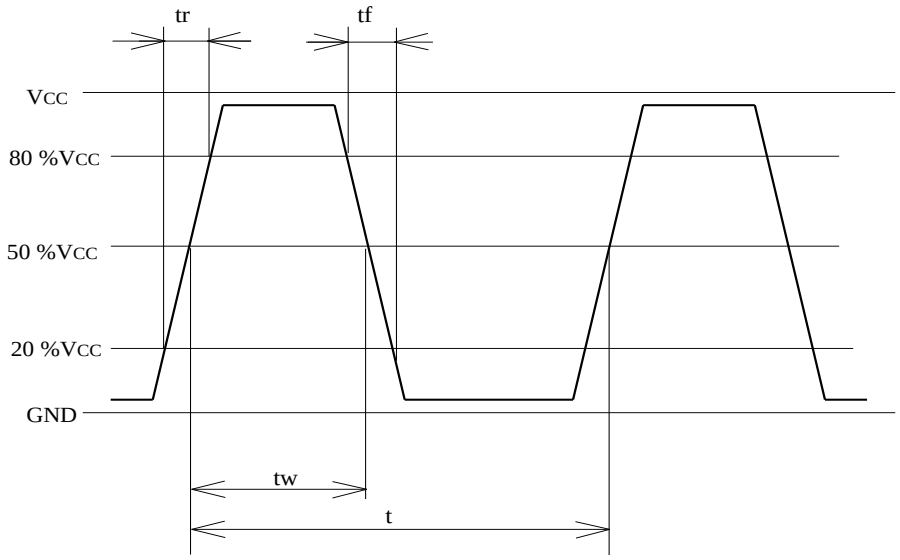
1.Absolute maximum ratings

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions / Remarks
Maximum supply voltage	Vcc-GND	-0.3	-	+7	V	-
Storage temperature	T_stg	-40	-	+125	ºC	Storage as single product
Input voltage	Vin	-0.5	-	Vcc+0.5	V	OE terminal

2.Specifications(characteristics)

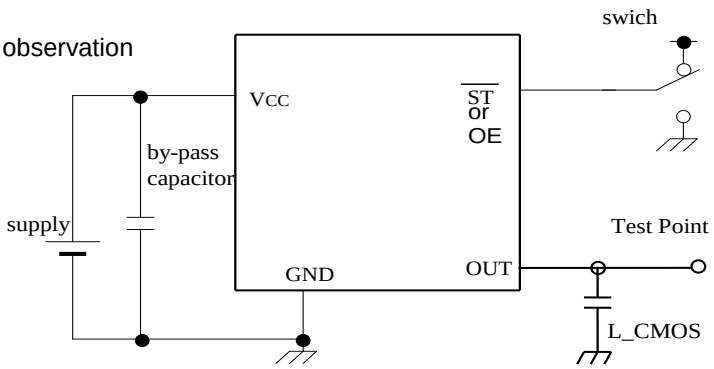
Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions / Remarks
Output frequency	f0		5.550000		MHz	
Supply voltage	Vcc	4.5	5	5.5	V	-
Operating temperature	T_use	-40	-	+85	ºC	-
Frequency tolerance	f_tol	-50	-	50	$x10^{-6}$	T_use
Current consumption	Icc	-	-	20	mA	No load condition
Stand-by current	I_std	-	-	-	µA	-
Disable current	I_dis	-	-	10.0	mA	OE = GND
Symmetry	SYM	40	-	60	%	50% Vcc Level L_CMOS=<50pF
Output voltage	V_{OH}	Vcc-0.4	-	-		-
	V_{OL}	-	-	0.4		-
Output load condition	L_CMOS	-	-	50	pF	CMOS Load
Input voltage	V_{IH}	0.8Vcc	-	-		OE terminal
	V_{IL}	-	-	0.2Vcc		OE terminal
Rise time	t_r	-	-	5	ns	0.2Vcc to 0.8Vcc Level, L_CMOS=50pF
Fall time	tf	-	-	5	ns	0.2Vcc to 0.8Vcc Level, L_CMOS=50pF
Start-up time	t_str	-	-	5	ms	t = 0 at 0.9Vcc
Jitter	t_{DJ}	-	-	-	ps	Deterministic Jitter
	t_{RJ}	-	-	-	ps	Random Jitter
	t_{RMS}	-	-	-	ps	σ(RMS of total distribution)
	t_{p-p}	-	-	-	ps	Peak to Peak
	t_{acc}	-	-	-	ps	Accumulated Jitter(σ), n = 2 to 50 000 cycles
Phase jitter	t_{PJ}	-	-	-	ps	Offset Frequency: 12 kHz to 20 MHz
Phase noise	L(f)	-	-	-	dBc/Hz	Offset 1 Hz
		-	-	-	dBc/Hz	Offset 10 Hz
		-	-	-	dBc/Hz	Offset 100 Hz
		-	-	-	dBc/Hz	Offset 1 kHz
		-	-	-	dBc/Hz	Offset 10 kHz, Vcc = 3.3 V
		-	-	-	dBc/Hz	Offset 100 kHz
		-	-	-	dBc/Hz	Offset 1 MHz
Frequency aging	f_age	-5	-	5	$x10^{-6}$	@+25ºC first year
		-	-	-		-

3.Timing chart

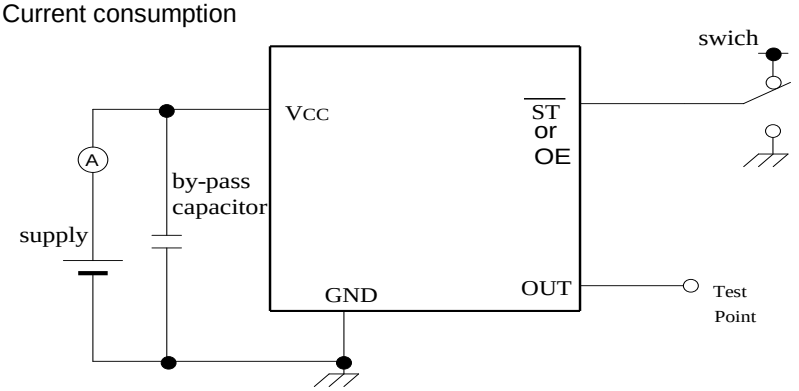


4.Test circuit

1) Waveform observation



2) Current consumption



*Current consumption under the disable function should be = GND.

3) Condition

(1) Oscilloscope

· Band width should be minimum 5 times higher (wider) than measurement frequency.

· Probe earth should be placed closely from test point and lead length should be as short as possible

* Recommendable to use miniature socket. (Don't use earth lead.)

(2) L_CMOS also includes probe capacitance.

(3) By-pass capacitor (0.01 µF to 0.1 µF) is placed closely between VCC and GND.

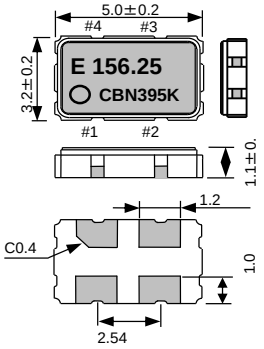
(4) Use the current meter whose internal impedance value is small.

(5) Power supply

· Start up time (0 %VCC to 90 %VCC) of power source should be more than 150 µs.

· Impedance of power supply should be as lowest as possible.

5.External dimensions (Unit: mm)



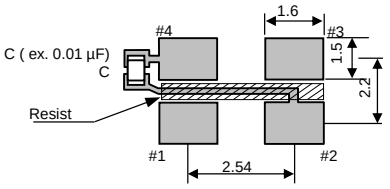
Pin map

Pin	Connection
1*	OE or ST
2	GND
3	OUT
4	Vcc

*) E function is only available SGxxxxCC H

Note.
OE pin = "H" or "open" : Specified frequency output.
OE pin = "L" : Output is high impedance.
ST pin = "H" or "open" : Specified frequency output.
ST pin = "L" : Output is high impedance、oscillation stops.

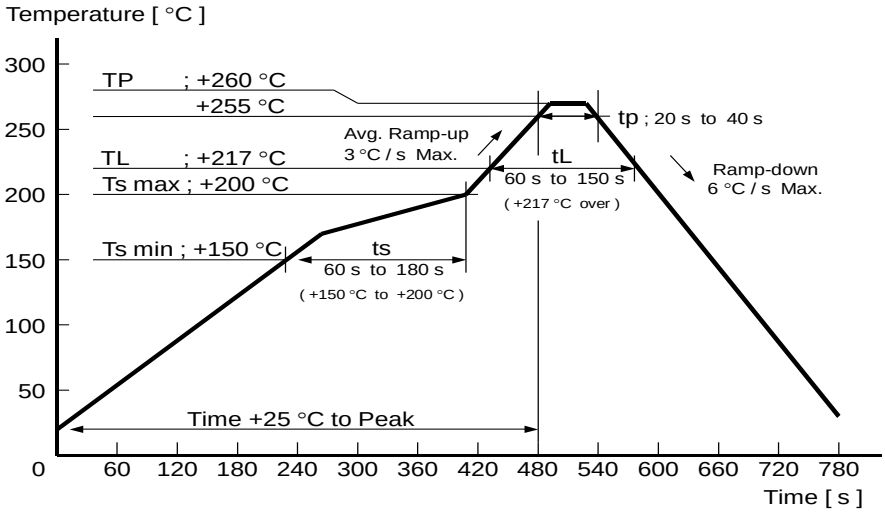
6.Footprint(Recommended) (Unit: mm)



To maintain stable operation, provide a 0.01uF to 0.1uF by-pass capacitor at a location as near as possible to the power source terminal of the crystal product (between Vcc - GND).

7.Reflow profile

Reflow condition (Follow of JEDEC STD-020D.01)



8.Packing information

[1]Product number last 2 digits code(xx) description The recommended code is "00"

X1G0044710039xx

Code	Condition	Code	Condition
01	Any Q'ty vinyl bag(Tape cut)	13	500pcs / Reel
11	Any Q'ty / Reel	00	1000pcs / Reel
12	250pcs / Reel		

[2] Taping specification

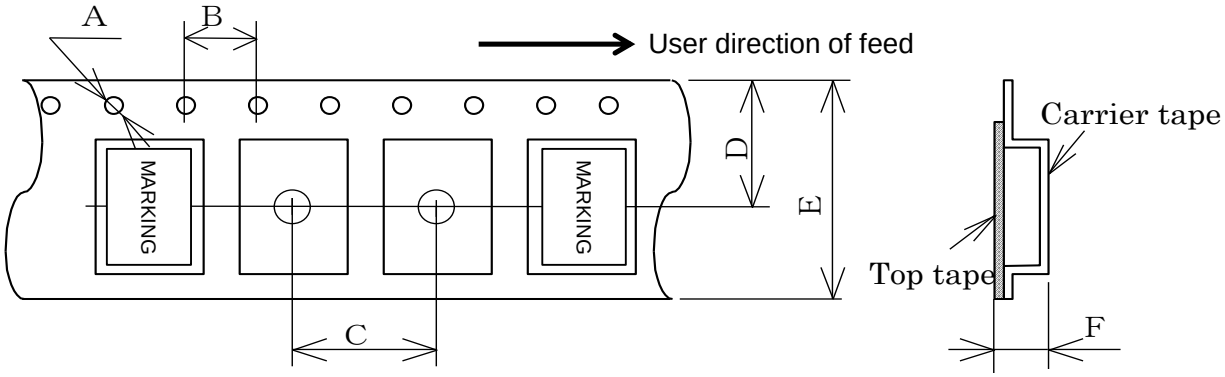
Subject to EIA-481 & IEC-60286

(1) Tape dimensions

Material of the Carrier Tape : PS

Material of the Top Tape : PET+PE

Unit: mm

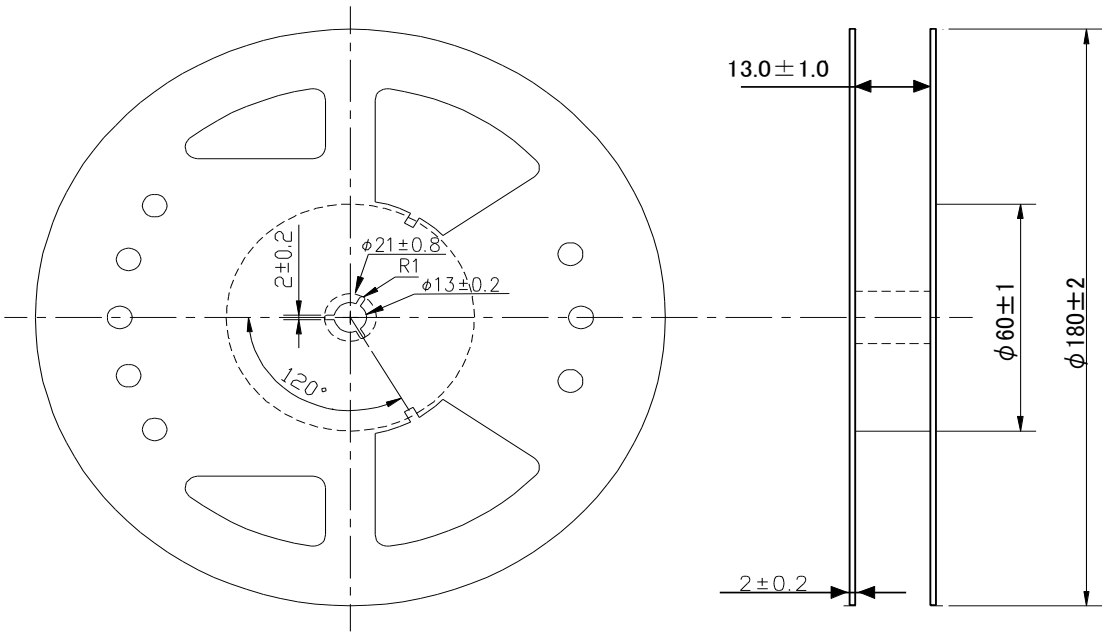


Symbol	A	B	C	D	E	F	G	H
Value	φ1.5 +0.1/-0	4.0±0.1	8.0±0.1	7.25±0.2	12.0±0.2	1.40±0.1	3.5±0.1	5.4±0.1

(2) Reel dimensions

Center material : PS

Material of the Reel : PS



9.Notice

- This material is subject to change without notice.
- Any part of this material may not be reproduced or duplicated in any form or any means without the written permission of Seiko Epson.
- The information about applied data,circuitry, software, usage, etc. written in this material is intended for reference only.
  Seiko Epson does not assume any liability for the occurrence of customer damage or infringing on any patent or copyright of a third party.
  This material does not authorize the licensing for any patent or intellectual copyrights.
- When exporting the products or technology described in this material, you should comply with the applicable export control laws and regulations and follow the procedures required by such laws and regulations.
- You are requested not to use the products (and any technical information furnished, if any) for the development and/or manufacture of weapon of mass destruction or for other military purposes. You are also requested that you
  would not make the products available to any third party who may use the products for such prohibited purposes.
- These products are intended for general use in electronic equipment. When using them in specific applications that require
  extremely high reliability, such as the applications stated below, you must obtain permission from Seiko Epson in advance.
  / Space equipment (artificial satellites, rockets, etc.)
  / Transportation vehicles and related (automobiles, aircraft, trains, vessels, etc.)
  / Medical instruments to sustain life
  / Submarine transmitters
  / Power stations and related
  / Fire work equipment and security equipment
  / Traffic control equipment
  / And others requiring equivalent reliability.

10.Contact us

www5.epsondevice.com/en/contact/